Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material	:
Metal	
Overall Length:	
Between 1.300 incl	nes and 1.310 inches
End Application:	
Md-3//md-4//ecu-10	05/e//ecu-110/e
Mounting Facility	Quantity:
1	
Electrode Internal	ly-electrically Connected To Case:
Anode	
Mounting Method	
Threaded stud	
Features Provided	l:
Mounting hardware	
Overall Width Acr	oss Flats:
Between 0.552 incl	nes and 0.562 inches
Thread Size:	
0.250 inches	
Semiconductor M	aterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
400.0 repetitive pe	ak off-state voltage and 400.0 repetitive peak reverse voltage and 5.0 peak gate voltage
Current Rating Pe	r Characteristic:
6.40 amperes forwa	ard current, total rms universal and 90.00 amperes forward current, total rms watts
Power Rating Per	Characteristic:
5.0 watts small-sigi	nal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal
Maximum Operati	ng Tempurature Per Measurement Point:
100.0 degrees cels	ius junction
Thread Series Des	signator:
Unf	
Terminal Type An	d Quantity:
1 threaded stud and	d 2 tab, solder lug
Specification Data	
75377-10692-014 r	nanufacturers specification control
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	